



Deep Learning (DL) Applications in Photomask to Wafer Semiconductor Manufacturing

Published by the eBeam Initiative Member Companies (March 2022)

Company: Advantest Corporation

Product and/or Application

Mask metrology system

DL techniques used: Deep convolutional neural networks (DCNNs) and etc.

DL benefits: Improving processing speed and accuracy for image recognition

Company: ASML

Product and/or Application

Newron Model

DL techniques used: Deep convolutional neural networks (DCNNs)

DL benefits: Significantly improves resist and etch model accuracy by capturing additional physical effects missed by conventional OPC models

Newron SRAF

DL techniques used: DCNNs

DL benefits: Generates SRAF placements based on inverse OPC at full chip application speed, thus significantly improves process window at similar compute cost

Newron OPC

DL techniques used: DCNNs

DL benefits: Accelerates OPC runtime significantly by reducing the number of iterations needed to achieve convergence

Company: Canon

Product and/or Application

Auto alignment function in lithography tool

DL techniques used: Convolutional neural networks (CNNs) – VGGNet and transfer-learning are used

DL benefits: Reducing unscheduled downtime with judging alignment target image usability, better and quicker than humans

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Company: CEA-LETI

Product and/or Application

Data preparation for grayscale lithography

SEM contour and CD metrology extraction on 2D & 3D features

SEM image denoising

DL techniques used: Deep learning solution developed internally

DL benefits: Accuracy improvement, treatment speed

Company: D2S

Product and/or Application

TrueMask® ILT GPU-accelerated, curvilinear full-chip ILT

DL techniques used: DCNNs and skip-connection (such as ResNet) based U-Net for the image-to-image translation

DL benefits: Speeds up full-chip ILT with a better starting point

TrueMask DLK Quick start DL kit

DL techniques used: DCNNs based deep Autoencoders (AE) for representing images

DL benefits: Robust deep learning applications created quickly with neural networks pre-trained for semiconductor manufacturing applications

CD-SEM Digital Twins

DL techniques used: Generative Adversarial Networks (GAN), Neural Image Synthesis

DL benefits: enables automated applications that analyze CD-SEM such as defect categorization, model extraction, etc.

Company: Fraunhofer IPMS

Product and/or Application

Simultaneous contour edge image prediction and SEM image denoising (please refer to <https://ieeexplore.ieee.org/abstract/document/9185250> joint paper with Texas A&M University)

DL techniques used: CNN LineNet2 trained with simulated training data set consisting of 32760 noisy SEM images with the corresponding original images and edge images

DL benefits: The method can be useful for real SEM image denoising, roughness estimation, and contour geometry estimation tasks

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Company: Hitachi High-Tech Corporation

Product and/or Application

Defect Review SEM

DL techniques used: DCNNs, etc.

DL benefits: Image quality enhancement for defect detection with high sensitivity

Company: imec

Product and/or Application

Deep learning applied to SEM images

DL techniques used: DCNNs, Residual Neural networks, Generative Adversarial Neural Networks

DL benefits: Super resolution enabled with faster acquisition, noise reduction with Generative Adversarial Networks (*Proceedings Volume 10959, Metrology, Inspection, and Process Control for Microlithography XXXIII*; 1095916 (2019) <https://doi.org/10.1117/12.2515182>)

Deep learning for improved process window analysis

DL techniques used: Autoencoder Neural Network

DL benefits: Provides fast proxy for CD metrology defining process window. Improves classification for OPC metrology needs.

Deep learning-driven Raman spectra quantification

DL techniques used: Deep fully connected neural networks, DCNNs

DL benefits: Automation of compositional extraction, convolutional approach for more bandwidth and sampling flexibility

Deep learning for defect classification and detection

DL techniques used: Deep fully connected neural networks, DCNNs

DL benefits: Automatic localization and classification of defects in SEM images enabling enhanced defect inspection for aggressive pitches. Pitch and noise invariant.

Deep learning-based SEM image denoiser

DL techniques used: Deep fully connected neural networks, DCNNs

DL benefits: Unsupervised deep learning training scheme without requirement clean noiseless images. Denoising reduces noise level only without altering the (real) information; no digital artefacts are introduced. Key process for working with thin resist or enabling contour detection capability.

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Company: NuFlare Technology, Inc.

Product and/or Application

SEM defect classifier

DL techniques used: Deep convolutional neural networks (DCNNs), skip-connection (such as ResNet) and Pix2Pix GANs

DL benefits: Reduce the downtime by speeding up the defect analysis and improving the classification accuracy. Defect analysis training, especially for young experts.

Log analysis

DL techniques used: Natural Language Processing (NLP)

DL benefits: Automatically detect the abnormalities from log with high accuracy.

Beam drift Prediction

DL techniques used: Long short-term memory (LSTM)

DL benefits: Improve mask drawing quality with automatic abnormal search and prediction.

Company: Siemens Industries Software, Inc.; Siemens EDA

Product and/or Application

Calibre Neural Network Assisted Modelling

DL techniques used: DCNNs for predicting, post exposure, post development and post etch contours

DL benefits: Improves accuracy as well as predictability of the models

Calibre Machine Learning OPC

DL techniques used: Neural networks with supervised learning for speeding up OPC

DL benefits: Up to 3X improvement in OPC speeds

Calibre LFD with Machine Learning

DL techniques used: Neural networks and data enrichment techniques for yield-limiters detection in the design flow

DL benefits: Order of magnitude speedup and improved coverage over standard techniques that result in improved design yield and reliability

Calibre Wafer Defect Engineering with Deep Learning

DL techniques used: Feature vector driven neural networks for layout analysis and hotspot detection

DL benefits: Robust applications that speed up test chip development and improves yield and reliability in the fab by quickly and efficiently detecting yield limiter

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Company: STMicroelectronics

Product and/or Application

Fab Digital Twin - automatic defect classification (ADC)

DL techniques used: CNNs

DL benefits: Corrective action in real time and defects are caught before other processes are added

Company: TASMIT

Product and/or Application

Semiconductor wafer metrology and inspection system

DL technique used: Recurrent neural networks (RNNs) for modeling time-series data such as historical logs, the sequence of events

DL benefits: High-speed quantitative estimation of photo resist shrinkage, charging, etc.

Semiconductor wafer metrology and inspection system

DL technique used: Generative Adversarial Networks (GANs) to create new data including images, text, etc.

DL benefits: High speed and high accuracy for CAD based image processing, CAD to SEM contour matching, and defect inspection performance

Semiconductor wafer metrology and inspection system

DL technique used: Anomaly detection using Gaussian Mixture Models (GMM), Generative Adversarial Networks (GANs) to identify irregularities, undesirable patterns in the data

DL benefits: Simple parameter setting for defect inspection

Semiconductor wafer metrology and inspection system

DL technique used: Extremely Randomized Trees (ERT) technology for the SEM contour extraction

DL benefits: High speed with lower cost of computer system for pattern edge detection